NSN 5961-00-893-9563

Transistor - Page 1 of 2



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Inclosure Material: Metal **Overall Length:** Between 0.500 inches and 0.560 inches Overall Diameter: Between 1.240 inches and 1.280 inches **Mounting Facility Quantity:** 1 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 25.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:**

Shelf Life: N/a

Unit Of Measure:

81349-mil-s-19500/102 government specification

NSN 5961-00-893-9563

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

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